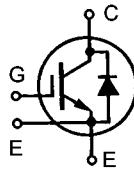


High Voltage IGBT with Diode

IXDN 55N120AU1

Short Circuit SOA Capability

Preliminary Data



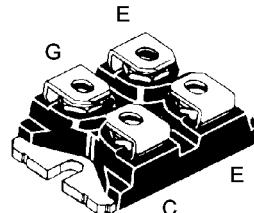
V_{CES} = 1200 V
 I_{C25} = 85 A
 $V_{CE(sat)\text{ typ}}$ = 2.5 V

Symbol	Test Conditions	Maximum Ratings		
V_{CES}	T_J = 25°C to 150°C	1200		V
V_{CGR}	T_J = 25°C to 150°C; $R_{GE} = 1 \text{ M}\Omega$	1200		V
V_{GES}	Continuous	±20		V
V_{GEM}	Transient	±30		V
I_{C25}	T_c = 25°C	85	A	
I_{C90}	T_c = 90°C	52	A	
I_{CM}	T_c = 25°C, 1 ms	170	A	
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 22 \Omega$ Clamped inductive load, $L = 30 \mu\text{H}$	$I_{CM} = 100$ @ V_{CES}		A
t_{sc} (SCSOA)	$V_{GE} = 15 \text{ V}$, $V_{CE} = V_{CES}$, $T_J = 125^\circ\text{C}$ $R_G = 22 \Omega$, non repetitive	10		μs
P_c	$T_c = 25^\circ\text{C}$	IGBT	450	W
V_{ISOL}	50/60 Hz $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	2500 3000	V~
T_J		-40 ... +150		°C
T_{JM}		150		°C
T_{stg}		-40 ... +150		°C
M_d	Mounting torque Terminal connection torque (M4)	1.5/13	Nm/lb.in. Nm/lb.in.	
Weight		30		g

Symbol	Test Conditions	Characteristic Values		
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.
BV_{CES}	$I_c = 5 \text{ mA}$, $V_{GE} = 0 \text{ V}$	1200		V
$V_{GE(\text{th})}$	$I_c = 2 \text{ mA}$, $V_{CE} = V_{GE}$	4	5.5	6.5 V
I_{CES}	$V_{CE} = V_{CES}$, $V_{GE} = 0 \text{ V}$ $V_{CE} = 0.8 \cdot V_{CES}$, $V_{GE} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	2.4 15	3 mA 19 mA
I_{GES}	$V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$			±500 nA
$V_{CE(sat)}$	$I_c = 50 \text{ A}$, $V_{GE} = 15 \text{ V}$	2.5	3	V

miniBLOC, SOT-227 B

E153432



E = Emitter *, C = Collector
G = Gate, E = Emitter *

* Either Emitter terminal can be used as Main or Kelvin Emitter

Features

- Square RBSOA
- International standard package miniBLOC
- Isolation voltage 3000 V~
- Low $V_{CE(sat)}$
 - for minimum on-state conduction losses
- High switching speed

Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

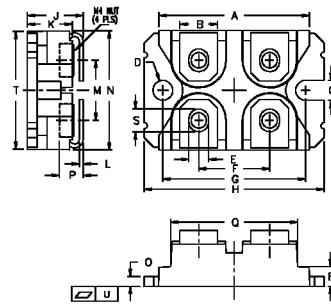
Advantages

- Space savings
- Easy to mount with 2 screws
- High power density

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	3300		pF
C_{oes}		500		pF
C_{res}		220		pF
Q_g	$I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}, V_{CE} = 0.5 V_{CES}$	TBD		nC
Q_{ge}		TBD		nC
Q_{gc}		TBD		nC
$t_{d(on)}$	Inductive load, $T_J = 125^\circ\text{C}$ $I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}, V_{CE} = 0.5 V_{CES}, R_{on/off} = 22 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) > $0.5 \cdot V_{CES}$, higher T_J or increased R_G	45	100	ns
t_{ri}		55	100	ns
$t_{d(off)}$		400	600	ns
t_{fi}		70	100	ns
E_{on}		8.5		mJ
E_{off}		4.8		mJ
R_{thJC}			0.28	K/W
R_{thCK}		0.1		K/W

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
V_F	$I_F = 50 \text{ A}, V_{GE} = 0 \text{ V},$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$	1.8	2.2	V
I_{RM}	$I_F = 50 \text{ A}, V_{GE} = 0 \text{ V}, -di_F/dt = 400 \text{ A}/\mu\text{s}$ $V_R = 600 \text{ V}$ $T_J = 100^\circ\text{C}$	28	35	A
t_{rr}	$I_F = 50 \text{ A}, V_{GE} = 0 \text{ V}, -di_F/dt = 400 \text{ A}/\mu\text{s}$ $V_R = 600 \text{ V}$ $T_J = 100^\circ\text{C}$ $I_F = 1 \text{ A}; -di/dt = 200 \text{ A}/\mu\text{s}; V_R = 30 \text{ V}$ $T_J = 25^\circ\text{C}$	200		ns
R_{thJC}		40	60	ns
			0.6	K/W

miniBLOC, SOT-227 B



M4 screws (4x) supplied

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	31.5	31.7	1.241	1.249
B	7.8	8.2	0.307	0.323
C	4.0	-	0.158	-
D	4.1	4.3	0.162	0.169
E	4.1	4.3	0.162	0.169
F	14.9	15.1	0.587	0.595
G	30.1	30.3	1.186	1.193
H	38.0	38.2	1.497	1.505
J	11.8	12.2	0.465	0.481
K	8.9	9.7	0.351	0.382
L	0.75	0.85	0.030	0.033
M	12.6	12.8	0.496	0.504
N	25.2	25.4	0.993	1.001
O	1.95	2.05	0.077	0.081
P	-	5.0	-	0.197